Direct measurement of the anisotropy of the resistivity in the *a-b* plane of twin-free, single-crystal, superconducting YBa₂Cu₃O_{7- δ}

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We have measured the resistivity tensor in one nearly twin-free crystal and one twin-free crystal of YBa₂Cu₃O₇₋₆. The first crystal was grown with a large twin-free region. We removed the twins in the second crystal by applying a uniaxial stress. Using a modified Montgomery technique, we measured the electrical resistivities in all three crystal directions and found them to be linear in temperature above the superconducting transition temperature T_c . Our results for ρ_a and ρ_b at room temperature are among the lowest that have been reported in the literature, indicating that our samples are of high quality. The ratio ρ_a / ρ_b is independent of temperature between 150 and 275 K, and its value, 2.2 ± 0.2 , indicates that the Cu-O chains contribute 60% of the current when the electric field is parallel to them, with the rest of the current being contributed by the Cu-O planes. This result, at zero frequency, is in good agreement with the recent conductivity at infrared frequencies obtained by Schlesinger *et al.*

I. INTRODUCTION

 $YBa_2Cu_3O_{7-\delta}$ is a high-temperature superconductor, and it has attracted much attention because of its unusual structure (containing Cu-O planes and chains) and its excellent properties (e.g., a sharp superconducting transition). Most measurements, including ours, have been made on material having a stoichiometry with δ near 0.1, correlated with a superconducting transition temperature T_c in excess of 90 K. Obtaining an understanding of the normal-state properties of YBa₂Cu₃O_{7-δ} is an important step toward understanding its superconducting properties. There have been many measurements of its resistivity in both polycrystalline and twinned single-crystal samples. In spite of these measurements, there is still doubt as to whether the *c*-axis resistivity, ρ_c , is linear in temper-ature,^{1,2} or has an upturn near T_c .^{3,4} Furthermore, no one has published results for the a-b resistivity anisotropy, ρ_a / ρ_b , because it has been difficult to make twin-free crystals of this compound. (The b direction is parallel to the Cu-O chains in our notation.) We report measurements of ρ_a / ρ_b for a nearly twin-free crystal and a twinfree crystal, analyzed with a modified Montgomery technique.^{5,6}

II. SAMPLE PREPARATION

The two single crystal samples used in this study were grown by a self-flux technique, as described elsewhere.⁷ We used yttria-stabilized zirconia crucibles instead of alumina crucibles to avoid aluminum impurities in our samples. These impurities greatly affect the *c*-direction resistivity.² Oxygenation was carried out during postgrowth annealing in flowing O_2 , first for 1 h at 600 °C and then for 96 h at 400 °C. This technique provides excellent single crystals, with sharp superconducting transitions.

The Montgomery method requires a sample with rectangular faces oriented parallel to the crystal axes. Our samples were rectangular, and their *ab* faces were nearly square; their dimensions are given in Table I. As grown, sample A had a large twin-free domain. It had been quenched in the tetragonal phase during crystal growth, as reported elsewhere.⁸ We cleaved this sample along the *a* and *b* crystal axes to remove the twinned regions and leave a nearly twin-free single crystal. (Magnetization measurements on sample A before the contacts were put onto it are reported elsewhere.⁸) Though grown in the same fashion as sample A, sample B had many twins, as do 95% of all crystals grown this way. We polished this

Sample	Axis	l' (µm)	$\alpha_i \ (\mu \Omega \ \mathrm{cm}/K)$	$\boldsymbol{\beta}_i \ (\mu \Omega \operatorname{cm})$	$\rho \ (\mu \Omega \ cm)$ $T = 100 \ K$	$\rho \ (\mu \Omega \ cm)$ T=275 K
A	a	530	0.554	-13.9	40	146
A	b	470	0.237	-2.81	21	68
A	с	24.0	12.5	1110	2300	4800
В	а	750	0.691	-13.0	53	178
В	b	865	0.269	-2.12	25	73
В	с	44.1	12.5	2220	3400	5600

TABLE I. Sample dimensions, linear fit parameters, $\rho_i(T) = \alpha_i T + \beta_i$ for 150 K < T < 220 K, and resistivities at 100 and 275 K.

crystal to a rectangular shape perpendicular to the a and b crystal axes, and removed all of its twin boundaries by applying a uniaxial stress at 450 °C in flowing oxygen on the hot stage of an optical microscope having crossed polarizers, as described previously.⁹ We examined both samples under crossed polarizers to look for twinning. One corner of sample A had a very small second twin domain in the vicinity of one contact. Sample B was untwinned. We believe, therefore, that the properties reported here for each sample were determined by a single domain.

The Montgomery analysis assumes that the sample has point contacts at the vertices of the crystal, so we made electrical contact through eight small gold pads placed as near to the corners of the *ab* faces as possible. We evaporated the gold pads onto the sample through a 30- μ mdiam hole in a mechanical mask. The distance from the edge of each contact to each adjacent edge of the sample was less than 10 μ m. Annealing the sample at 400 °C for 48 h in flowing O₂ made the gold pads stick to the surface and reduced the contact resistance from ~1 k Ω to ~1 Ω .

The contact application procedure did not affect the bulk properties of our crystals. The dc magnetization of the crystals as measured in a superconducting quantum interference device magnetometer after the final heat treatment showed a very sharp (<2 K wide) bulk transition (Fig. 1). Secondary-ion mass spectrometry (SIMS) performed on a similarly prepared twinned crystal demonstrated that the depth of gold diffusion after such a heat treatment was <0.2 μ m in the c direction of the sample.



FIG. 1. Magnetic susceptibility χ vs temperature *T*. Zero-field-cooled (ZFC) and field-cooled (FC) data are shown.

III. MEASUREMENTS AND METHODS

We thermally anchored each sample to a copper grid with General Electric GE7031 varnish, allowing access to all eight corners, and we made final electrical contact to the crystals, using a micromanipulator and silver paste to attach 25- μ m-diam gold wires to the contact pads. The diameter of contact of the silver paste was approximately 50-100 μ m, larger than the 30- μ m-diam gold contact pad. No additional heat treatment was necessary to achieve low contact resistances. Since silver paste does not make good electrical contact to YBa₂Cu₃O_{7.8} crystals without a heat treatment, the effective contact diameter is that of the gold pad.

We monitored the sample temperature with a calibrated platinum resistor, and took data only after achieving thermal equilibrium. We stabilized the temperature to within 1 mK for 80 K < T < 110 K and to within 10 mK for T > 110 K.

We measured the Montgomery resistances, $R_{ij} = V/I$, for the configuration of leads schematically shown in Fig. 2, using a computer-controlled, calibrated ac bridge¹⁰ operated at 50 Hz and a current of 600 μ A. The results were insensitive to the size of the current. R_{ii} is the resistance when the current nominally flows in the *i* direction and the four contacts are configured on or near the ij face. Rotating the lead configuration on the crystal by 90° gives the resistance R_{ji} , so we were able to measure six R_{ij} configurations: two on each of the *ab*, *bc*, and *ca* faces. Ideally, only three such measurements are necessary to determine the resistivities; our six measurements overdetermine the parameters, providing a consistency check. Below T_c , R_{ij} is apparently small but positive $(\sim 10^{-4} \Omega, \text{ too small to see in Figs. 2 and 3), and in$ dependent of temperature, but varying with frequency, current, and lead configuration. This small instrumental offset was subtracted from the data. Figure 2-5 show the R_{ij} as a function of temperature.



FIG. 2. Montgomery resistances R_{ij} and their fitted values R_{ij}^{fi} vs T for sample A. Note: we perform a new fit to the R_{ij} at each temperature. Inset: schematic diagram of the contact geometry on one face of the sample.



FIG. 3. Montgomery resistances R_{ij} and their fitted values R_{ij}^{fit} vs T for sample B.

IV. RESISTIVITY CALCULATIONS

To determine the resistivities, ρ_i , from the R_{ij} data, we combine van der Pauw's¹¹ mapping between equivalent anisotropic and isotropic crystals, Eqs. (1) and (2), with the calculation by Logan, Rice, and Wick⁶ (LRW) of R_{ij} for an isotropic crystal, Eqs. (3) and (4). The mapping of van der Pauw,

$$l_i = l_i' \left[\frac{\rho_i}{\rho}\right]^{1/2},\tag{1}$$

$$\rho = (\rho_1 \rho_2 \rho_3)^{1/3} , \qquad (2)$$

determines the dimensions, l_i , and resistivity, ρ , of an isotropic crystal that has the same R_{ij} values as a rectangular crystal with edges aligned with the principal axes of the resistivity tensor and having the lengths l'_i . For such an isotropic crystal, LRW found

$$R_{ij} = \frac{8l_j\rho}{l_i l_k} \sum_{\substack{m=1\\m \text{ odd}}}^{\infty} \sum_{n=0}^{\infty} \frac{\epsilon_n}{S_{ijmn} \sinh(S_{ijmn})} , \qquad (3)$$

where $\epsilon_0 = 1$; $\epsilon_n = 2$ for $n \neq 0$; i, j, and k are distinct, and



FIG. 4. A magnification of part of Fig. 2.



FIG. 5. A magnification of part of Fig. 3.

$$S_{ijmn}^2 = \pi^2 m^2 \left[\frac{l_j}{l_i} \right]^2 + \pi^2 n^2 \left[\frac{l_j}{l_k} \right]^2.$$
⁽⁴⁾

Substituting van der Pauw's mapping into the LRW formulas, we find

$$R_{ij} = \frac{8l'_j \rho_j}{l'_i l'_k} \sum_{\substack{m=1\\m \text{ odd}}}^{\infty} \sum_{n=0}^{\infty} \frac{\epsilon_n}{S_{ijmn} \sinh(S_{ijmn})} , \qquad (5)$$

$$S_{ijmn}^{2} = \pi^{2} m^{2} \left[\frac{l_{j}'}{l_{i}'} \right]^{2} \left[\frac{\rho_{j}}{\rho_{i}} \right] + \pi^{2} n^{2} \left[\frac{l_{j}'}{l_{k}'} \right]^{2} \left[\frac{\rho_{j}}{\rho_{k}} \right] .$$
(6)

We must find the resistivities, ρ_i , that satisfy these equations.

By performing a nonlinear, least-squares fit to the R_{ij} values, using a modification of the implementation of Press *et al.*¹² of the Levenberg-Marquardt algorithm, we computed a different set of resistivities (ρ_a, ρ_b, ρ_c) at each temperature. Our computations iteratively reduce the sum of the squares of the fractional deviations of the fit from the data:

$$\chi^2 = \sum \left[\frac{(R_{ij}^{\text{fit}} - R_{ij})}{R_{ij}} \right]^2.$$
⁽⁷⁾

The sum is over the data points, at each temperature. By weighting the R_{ij} values equally, this form of χ^2 preserves the significance of all the data, regardless of their magnitudes; this is crucial because our data span up to five decades at a given temperature. In fitting the measurements, we chose to discard the R_{31} points because the signal to noise ratio was too low. Figure 6 and 7 show the calculated resistivities.

Our use of a fitting algorithm and the threedimensional R_{ij} formulas, Eqs. (5) and (6), deviates from the analysis of Montgomery. His method demands (a) that two of the resistivity tensor's eigenvalues be degenerate, (b) that the crystal be electrically thick $[l_k \gg (l_i l_j)^{1/2}]$ or thin $[l_k \ll (l_i l_j)^{1/2}]$, or (c) that we ignore the variation of R_{ij}/R_{ji} with l_k . Our goal is to



FIG. 6. The resistivity tensor's eigenvalues ρ_a , ρ_b , and ρ_c vs T for sample A. The values of ρ_c are not precisely determined; see the text.

differentiate between resistivities in all three directions, and our samples are not electrically thick or thin for all contact configurations. Though in a first approximation we can ignore the variation of R_{ij}/R_{ji} with l_k and use calibration curves as Montogomery did, it is more precise to make a three-dimensional calculation. Additionally, we have more than the minimum number of data to determine the ρ_i values, and an examination of χ^2 provides us with a simple consistency check.

Both data sets indicate that the superconducting transition begins near 96 K; the zero-resistance temperature was near 92 K. The fits to the data below 96 K were not good for sample A, with large χ^2 values. Similarly bad χ^2 values occurred for sample B but below 94 K. The reason for this deviation is unknown; probably the samples are electrically less homogeneous near T_c . The data for T > 96 K were fitted to within 2% with small systematic deviations, as can be seen in Figs. 2–4. The systematic deviations seen there could be caused (a) by sample inhomogeneity or (b) by nonideal contacts of finite area, slightly displaced from the corners. The value of ρ_c



FIG. 7. The resistivity tensor's eigenvalues ρ_a , ρ_b , and ρ_c vs T for sample B. The values of ρ_c are not precisely determined; see the text.

is critically dependent on R_{32} because R_{32} is the only configuration used in the fit for which the current is principally in the *c* direction. (The noise in the data for R_{32} is directly seen in the ρ_c versus *T* plots of Figs. 6 and 7.) Any systematic errors in the data for R_{32} are transformed into errors in ρ_c . The magnitude of R_{32} is small because the crystals are thin. Thus, our values of ρ_c are not very precise and should not be used in place of those already published by other groups on samples with more favorable shapes. It should be noted that our results for ρ_a and ρ_b are not very sensitive to the value of ρ_c because the samples are thin. The total uncertainties in the calculated values of ρ_a and ρ_b in each sample appear to be less than the variation from sample *A* to sample *B*.

V. RESULTS

Figure 8 shows the anisotropy ratio ρ_a/ρ_b for both samples. We conclude that the ρ_a/ρ_b anisotropy is 2.2±0.2 between 150 and 275 K. The enhanced conductivity in the *b* direction shows the influence of the Cu-O chains.

Our results for ρ_a and ρ_b at room temperature are among the lowest that have been reported in the literature, indicating that our samples are of high quality. At room temperature $\rho_c \approx 5.3 \text{ m}\Omega \text{ cm}$, which is lower than the range of $8-20 \text{ m}\Omega \text{ cm}$ reported by others,²⁻⁴ but this is the direction for which the uncertainty in our results is large. We can compare ρ_c/ρ_a and ρ_c/ρ_b to the measurements of ρ_c/ρ_{ab} by other groups, where ρ_{ab} is the planar resistivity in twinned crystals. Their values range from 30 to 100 at room temperature and 52 to 250 at 100 K.²⁻⁴ At 275 K, we find $\rho_c/\rho_a \sim 35$ and $\rho_c/\rho_b \sim 75$, while at 100 K, $\rho_c/\rho_a \sim 63$ and $\rho_c/\rho_b \sim 120$, within the previously published ranges of values.

The resistivities in all three directions are linear in temperature. Table I summarizes the fits of the resistivities to linear functions of temperature $\rho_i(T) = \alpha_i T + \beta_i$ for 150 K < T < 220 K for each crystal. The intercepts for $\rho_b(T)$ are nearly zero for both samples, since $\beta_b \approx -2.5$ $\mu\Omega$ cm, while those for $\rho_a(T)$ are both negative, with $\beta_a \approx -13.5 \mu\Omega$ cm. As shown in Figs. 6 and 7, when T is



FIG. 8. Resistivity ratio ρ_a / ρ_b vs T for samples A and B.

reduced toward T_c , ρ_a deviates from linearity in a manner indicating fluctuations of small regions of the sample into the superconducting state. This type of deviation is also seen for ρ_b , but is smaller in magnitude. The resistivities deviate from linearity above 240 K, possibly indicating anomalous behavior near that temperature, as seen in many other types of experiments.^{13,14}

By taking the geometric mean of ρ_a and ρ_b at room temperature, we can calculate an effective in-plane resistivity for our twin-free samples; $\rho_{ab} = (\rho_a \rho_b)^{1/2} = 110$ $\mu\Omega$ cm. This value falls below those of the best twinned crystals, $\rho_{ab} = 150$ to 250 $\mu\Omega$ cm,^{2-4,15} indicating that twin boundaries significantly increase the planar resistivities.

The resistivity in the b direction is significantly less than that in the a direction. Naively, we separate the chain conductivity from the plane conductivity. Assuming that the a direction conductivity is the intrinsic plane conductivity and that the b direction conductivity contains contributions from both the planes and the chains, we have

$$\sigma_b = \sigma_{\text{chain}} + \sigma_{\text{plane}} , \qquad (8)$$
$$\sigma_a = \sigma_{\text{plane}} .$$

This gives for the chain and plane conductivity at room temperature:

$$\sigma_{\text{chain}} = 0.0084 \ (\mu \Omega \text{ cm})^{-1} ,$$

$$\sigma_{\text{plane}} = 0.0056 \ (\mu \Omega \text{ cm})^{-1} ,$$

$$\frac{\sigma_{\text{chain}}}{\sigma_{\text{chain}} + \sigma_{\text{plane}}} = 0.60 .$$
(9)

Far-infrared measurements were recently made by Schlesinger et al.¹⁶ on twin-free samples of YBa₂Cu₃O_{7.8}. The data indicate that 50-60 % of the infrared conductivity is associated with the chains. This agrees well with our result of 60%. It should be noted, however, that Schlesinger et al. extrapolate their conductivity measurements to zero frequency and find that the a-b anisotropy would be only 10 - 30%whereas we find $\rho_a/\rho_b = 2.2 \pm 0.2$. The extrapolation to zero frequency is difficult, in our opinion.

VI. CONCLUSIONS

We have measured the anisotropy of the resistivity in twin-free single crystals of YBa₂Cu₃O_{7.8}. The dc anisotropy ratio ρ_a/ρ_b has been determined for the first time. Between 150 and 275 K, the anisotropy ratio ρ_a/ρ_b is temperature independent and is equal to 2.2±0.2. This result is in good agreement with the recent infrared conductivity data of Schlesinger *et al.*

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